

# ESDONCAN1, SESDONCAN1

## CAN/CAN-FD Bus Protector

### Low Capacitance ESD Protection Diode for CAN/CAN-FD Bus

The S/ESDONCAN1 has been designed to protect the CAN transceiver from ESD and other harmful transient voltage events. This device provides bidirectional protection for each data line with a single compact SOT-23 package, giving the system designer a low cost option for improving system reliability and meeting stringent EMI requirements.

#### Features

- 200 W Peak Power Dissipation per Line (8 x 20  $\mu$ sec Waveform)
- Diode Capacitance Matching
- Low Reverse Leakage Current (< 100 nA)
- Low Capacitance High-Speed FlexRay Data Rates
- IEC Compatibility:
  - IEC 61000-4-2 (ESD): Level 4
  - IEC 61000-4-4 (EFT): 50 A – 5/50 ns
  - IEC 61000-4-5 (Lighting) 3.0 A (8/20  $\mu$ s)
- ISO 7637-1, Nonrepetitive EMI Surge Pulse 2, 8.0 A (1 x 50  $\mu$ s)
- ISO 7637-3, Repetitive Electrical Fast Transient (EFT) EMI Surge Pulses, 50 A (5 x 50 ns)
- Flammability Rating UL 94 V-0
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

#### Typical Applications

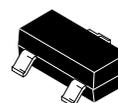
- Industrial
  - ◆ Smart Distribution Systems (SDS)
  - ◆ DeviceNet
- Automotive
  - ◆ Controlled Area Network – CAN 2.1 / CAN FD
  - ◆ Low and High Speed CAN



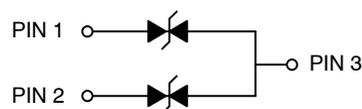
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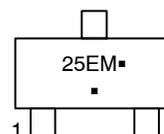
**SOT-23  
DUAL BIDIRECTIONAL  
VOLTAGE SUPPRESSOR  
200 W PEAK POWER**



SOT-23  
CASE 318  
STYLE 27



#### MARKING DIAGRAM



25E = Device Code  
M = Date Code  
■ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# ESDONCAN1, SESDONCAN1

## MAXIMUM RATINGS (T<sub>J</sub> = 25°C, unless otherwise specified)

Symbol	Rating	Value	Unit
PPK	Peak Power Dissipation, 8 x 20 μs Double Exponential Waveform (Note 1)	200	W
T <sub>J</sub>	Operating Junction Temperature Range	-55 to 150	°C
T <sub>J</sub>	Storage Temperature Range	-55 to 150	°C
T <sub>L</sub>	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM)	8.0	kV
	Machine Model (MM)	400	V
	IEC 61000-4-2 Specification (Contact)	23	kV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Non-repetitive current pulse per Figure 1.

## ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V <sub>RWM</sub>	Reverse Working Voltage	(Note 2)	24	-	-	V
V <sub>BR</sub>	Breakdown Voltage	I <sub>T</sub> = 1 mA (Note 3)	26.2	-	32	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 24 V	-	15	100	nA
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 1 A (8 x 20 μs Waveform) (Note 4)	-	33.4	36.6	V
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 3 A (8 x 20 μs Waveform) (Note 4)	-	44	50	V
I <sub>PP</sub>	Maximum Peak Pulse Current	8 x 20 μs Waveform (Note 4)	-	-	3.0	A
C <sub>J</sub>	Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)	-	-	10	pF
ΔC	Diode Capacitance Matching	V <sub>R</sub> = 0 V, 5 MHz (Note 5)	-	0.26	2	%

2. TVS devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.
4. Pulse waveform per Figure 1.
5. ΔC is the percentage difference between C<sub>J</sub> of lines 1 and 2 measured according to the test conditions given in the electrical characteristics table.

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
ESDONCAN1LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SESDONCAN1LT1G*	SOT-23 (Pb-Free)	3,000 / Tape & Reel
ESDONCAN1LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
SESDONCAN1LT3G*	SOT-23 (Pb-Free)	10,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

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## TYPICAL PERFORMANCE CURVES

( $T_J = 25^\circ\text{C}$  unless otherwise noted)

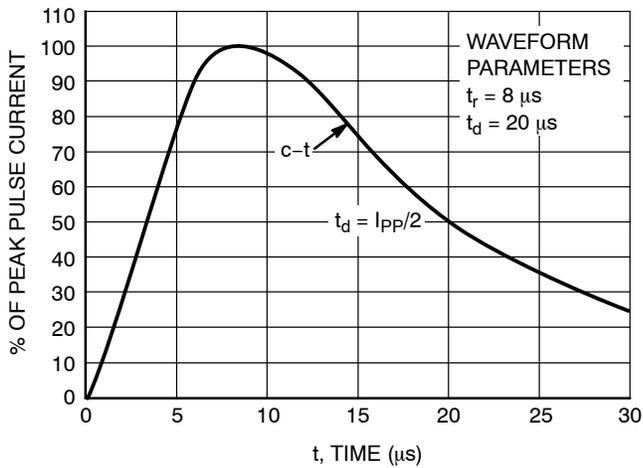


Figure 1. Pulse Waveform,  $8 \times 20 \mu\text{s}$

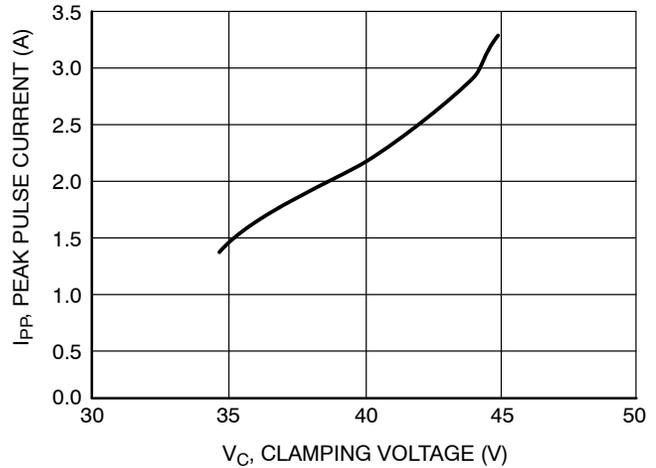


Figure 2. Clamping Voltage vs Peak Pulse Current

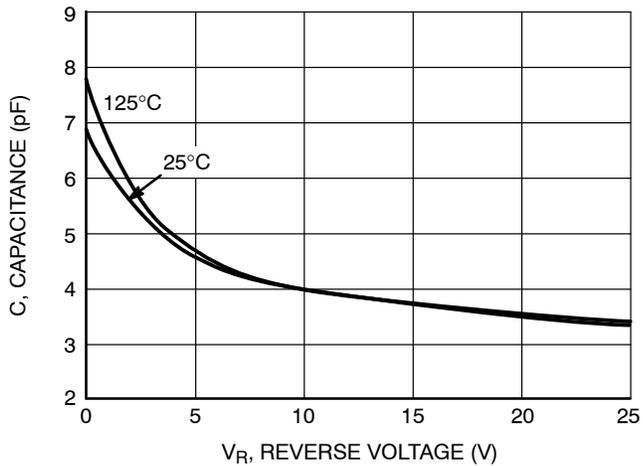


Figure 3. Typical Junction Capacitance vs Reverse Voltage

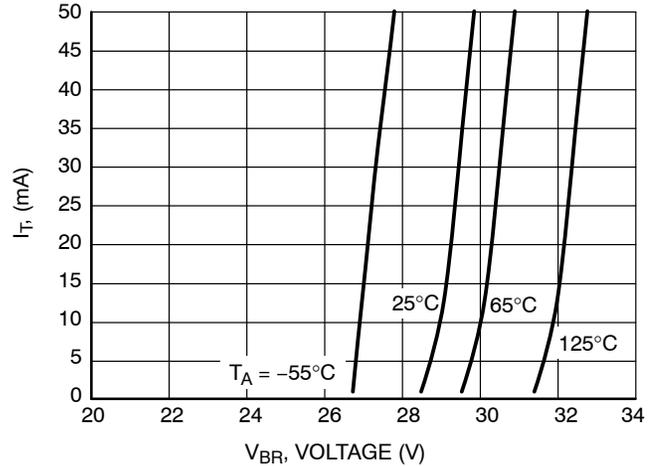


Figure 4.  $V_{BR}$  versus  $I_T$  Characteristics

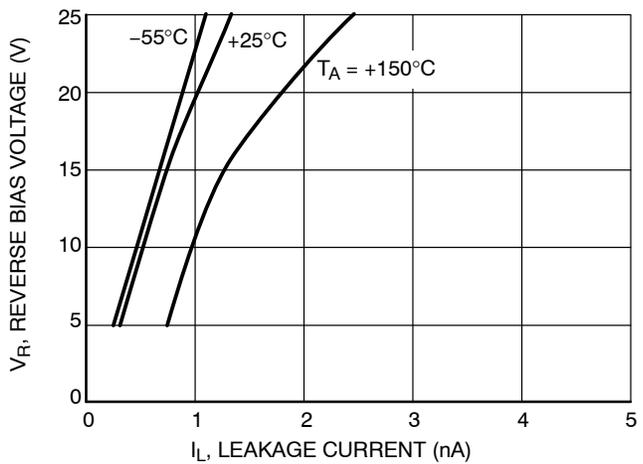


Figure 5.  $I_R$  versus Temperature Characteristics

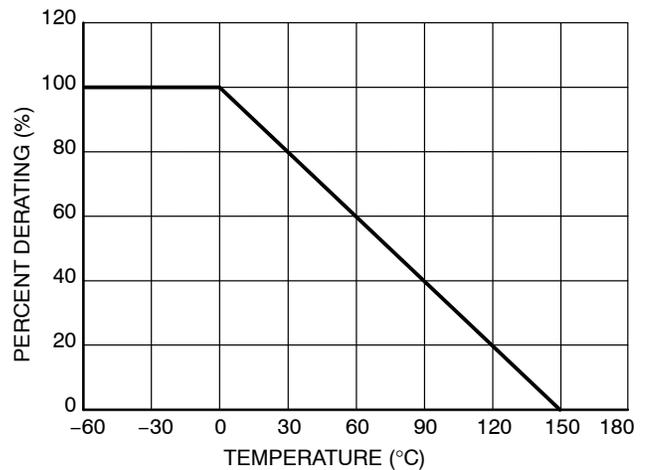


Figure 6. Temperature Power Dissipation Derating

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## APPLICATIONS

### Background

The Controller Area Network (CAN) is a serial communication protocol designed for providing reliable high speed data transmission in harsh environments. TVS diodes provide a low cost solution to conducted and radiated Electromagnetic Interference (EMI) and Electrostatic Discharge (ESD) noise problems. The noise immunity level and reliability of CAN transceivers can be easily increased by adding external TVS diodes to prevent transient voltage failures. The ESDONCAN1 provides a transient voltage

suppression solution for CAN data communication lines. The ESDONCAN1 is a low capacitance dual bidirectional TVS device in a compact SOT-23 package especially suitable for CAN2.1 (CAN-FD). This device is based on Zener technology that optimizes the active area of a PN junction to provide robust protection against transient EMI surge voltage and ESD. The ESDONCAN1 has been tested to EMI and ESD levels that exceed the specifications of popular high speed CAN networks.

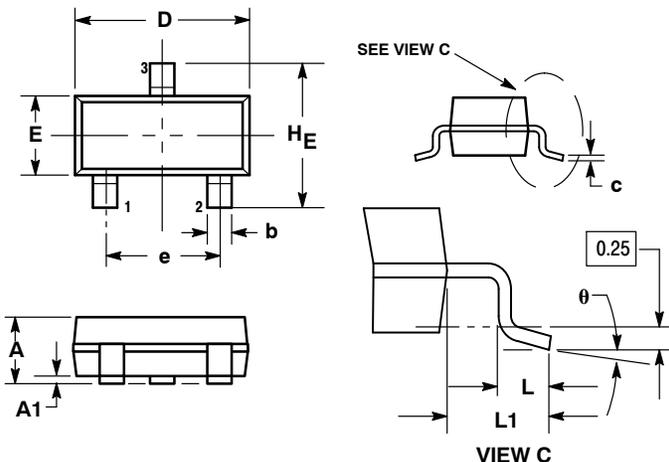
# ESDONCAN1, SESDONCAN1

## PACKAGE DIMENSIONS

SOT-23 (TO-236)

CASE 318-08

ISSUE AP



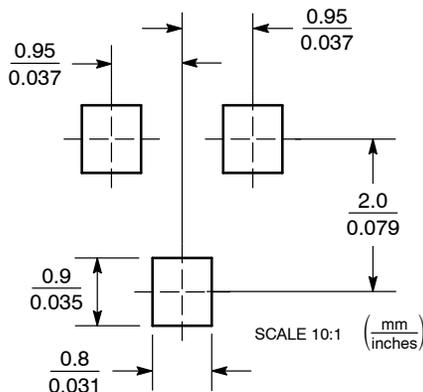
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°	---	10°	0°	---	10°

STYLE 27:  
PIN 1. CATHODE  
2. CATHODE  
3. CATHODE

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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P.O. Box 5163, Denver, Colorado 80217 USA  
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
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### Офис по работе с юридическими лицами:

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